# AC6329C Datasheet

# Zhuhai Jieli Technology Co.,LTD

Version: V1.0

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### **AC6329C Features**

#### High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

#### Flexible I/O

- 10 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

#### **Peripheral Feature**

- One Full Speed USB OTG controller
- Four Multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex advanced UART(DMA)
- Three SPI interface supports host and device mode (DMA)
- One IIC interface supports host and device mode
- RTC, with alarm clock and time base to wake up the chip
- 16-bit PWM generator for motor driving
- Three IQ Encoder
- 6 channels 10-bit ADC

- 1 channel 8 levels Low Power Detector
- Embedded PMU support low power mode
- Watchdog
- Power-on reset

#### **Bluetooth Feature**

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth
- **♥** V5.0+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides +8dbm transmitting power
- Receiver with -92dBm sensitivity
- Support a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\ gatt\rfcomm\sdp\l2cap profile

#### **Power Supply**

- **LDOIN** is 4.5V to 5.5V
- **VBAT** is 1.8V to 4.5V
- VDDIO is 1.8V to 3.4V

#### **Packages**

SOP16

#### **Temperature**

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

## 1. Block Diagram

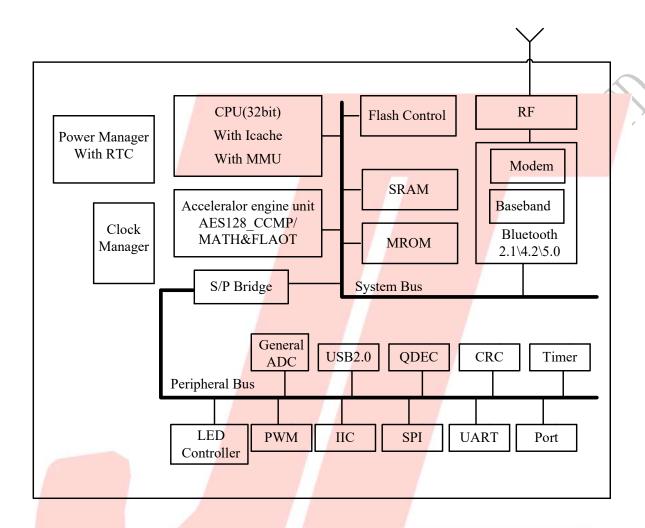


Figure 1-1 AC6329C\_SOP16 Block Diagram

### 2. Pin Definition

### 2.1 Pin Assignment

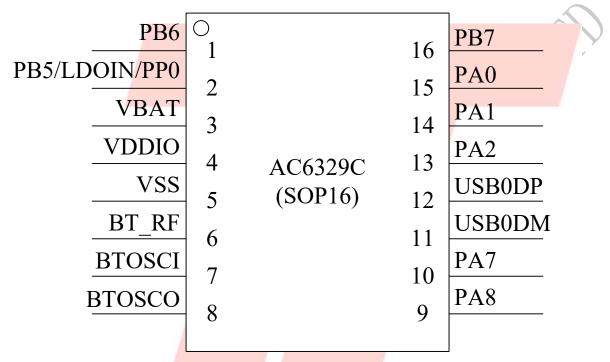


Figure 2-1 AC6329C SOP16 Package Diagram

### 2.2 Pin Description

Table 2-1 AC6329C\_SOP16 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	PB6	I/O	GPIO	SPI2_CLKA: SPI2 Clock(A); ADC12: ADC Channel 12; UART2_TXC: Uart2 Data Out(C); TMR3CK;
	PB5	I/O	GPIO (High Voltage)	SPI2_DIA: SPI2 Data In(A); UART1_RXA: Uart1 Data In(A); PWMCH3L;
2	LDOIN/PP0	P	Charge Power 5V	PWM3: Timer3 PWM Output;  UART0_TXD: Uart0 Data Out(D);  UART0_RXD: Uart0 Data In(D);
3	VBAT	P	LDO Power	
4	VDDIO	P	IO Power 3.3V	- / /
5	VSS	P	GND	-
6	BT_RF	-	RF Antenna	-
7	BTOSCI	I	BTOSCI	-
8	BTOSCO	0	BTOSCO	-
9	PA8	I/O	GPIO	TMR3: Timer3 Clock In;  SPI1_DOA: SPI1 Data Out(A);  IIC_SDA_C: IIC SDA(C);  ADC4: ADC Channel 4;  UART1_RXC: Uart1 Data In(C);  PWMCH1L;
10	PA7	I/O	GPIO	TMR1: Timer1 Clock In; SPI1_CLKA: SPI1 Clock(A); IIC_SCL_C: IIC SCL(C); ADC3: ADC Channel 3; UART1_TXC: Uart1 Data Out(C); PWMCH1H;
11	USB0DM	I/O	GPIO (pull down)	SPI2_DOB: SPI2 Data Out(B); IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);

				SPI2_CLKB: SPI2 Clock(B);		
12	12 LIGDODD LI	I/O	GPIO	IIC_SCL_A: IIC SCL(A);		
12	USB0DP	1/0	(pull down)	ADC10: ADC Channel 10;		
				UART1_TXD: Uart1 Data Out(D);		
				CAP3: Timer3 Capture;		
13	PA2	I/O	GPIO	Q-decoder0_1;		
13	r A2	1/0	GFIO	UART0_RXC: Uart0 Data In(C);		
				UART1_RTS;		
				PWM0: Timer0 PWM Output;		
						Q-decoder0_0;
14	PA1	I/O	GPIO	ADC0: ADC Channel 0;		
			/	UART0_TXC: Uart0 Data Out(C);		
				UART1_CTS;		
				CLKOUT1;		
15	PA0	I/O	GPIO	UART2_TXB: Uart2 Data Out(B);		
13	PA0 I/O	(High Voltage)	UART2_RXB: Uart2 Data In(B);			
				PWMCH0H;		
16	DD7	1/0	GPIO	SPI2_DOA: SPI2 Data Out(A);		
10	16 PB7 I/O		(High Voltage)	UART2_RXC: Uart2 Data In(C);		

### 3. Electrical Characteristics

### 3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
LDOIN	Charge Input Voltage	-0.3	6	V
VDDIO	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

### 3.2 Recommended Operating Conditions

Table 3-2

I	Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
ſ	VBAT	Voltage Input	1.8	3.7	4.5	V	_
ſ	LDOIN	Voltage Input	4.5	5.0	5.5	V	_
1	VDDIO	Voltage output	1.8	3.0	3.4	V	VBAT= 4.2V, 60mA loading
ſ	BTAVDD	Voltage output	1	1.3	1.4	V	DC-DC mode: 40mA loading
	I <sub>VDDIO</sub>	Loading current	1		60	mA	VBAT = 4.2V

### 3.3 Battery Charge

Table 3-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
LDOIN	Charge Input Voltage	4.5	5	5.5	V	_
$ m V_{Charge}$	Charge Voltage	4.15	4.2	4.25	V	-
ICharge	Charge Current	20		200	mA	Charge current at fast charge mode
${ m I}_{ m Trikl}$	Trickle Charge Current	20	45	70	mA	$V_{BAT} < V_{Trikl}$

### 3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
$V_{I\!L}$	Low-Level Input Voltage	-0.3	_	0.3* VDDIO	V	VDDIO = 3.3V
$V_{\mathrm{IH}}$	High-Leve <mark>l Input</mark> Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V
IO output	characterist <mark>ics</mark>					
V <sub>OL</sub>	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V
V <sub>OH</sub>	High-Level Output Voltage	2.7	_	7-	V	VDDIO = 3.3V

### 3.5 Internal Resistor Characteristics

Table 3-5

Port	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA1-PA9, PB6,	drive_select[11] 24mA drive_select[10] 24mA (with 120ohm res) drive_select[01] 8mA drive_select[00] 8mA (with 120ohm res)	10K	10K	1. USB0DM&USB0DP default pull down 2. Internal pull-up/pull-down resistance   accuracy ±20%
PA0,PB5, PB7,	8mA	10K	10K	5.PA0,PB5,PB7 can pull-up resistance to 5V
USB0DP	4mA	1.5K	15K	
USB0DM	4mA	180K	15K	

### 3.6 BT Characteristics

#### 3.6.1 Transmitter

**Basic Data Rate** 

Table 3-6

Busic Butu Rute		Tubic 5				
Paramete	r /	Min	Тур	Max	Unit	<b>Test Conditions</b>
RF Transmit P	ower		4	6	dBm	
RF Power Contro	ol Range		20		dB	25°C,
20dB Bandw	idth		950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38	7//	dBm	VBAT=5V
Transmit Power	+3MHz		-44	7./	dBm	2441MHz
	-3MHz		-35		dBm	

#### **Enhanced Data Rate**

Table 3-7

Paramete	Min	Тур	Max	Unit	Test Conditions	
Relative Po		-1		dB		
π/4 DQPSK	DEVM RMS		7		%	
	DEVM 99%		12		%	25°C,
Modulation Accuracy	DEVM Peak	7	17	7	%	Power Supply
	+2MHz		-40		dBm	VBAT=5V
Adjacent Channel	-2MHz		-38		dBm	2441MHz
Transmit Power	+3MHz		-44		dBm	
	-3MHz	7/	-35		dBm	V.

#### 3.6.2 Receiver

**Basic Data Rate** 

**Table 3-8** 

Paramete	er	Min	Тур	Max	Unit	Test Conditions
Sensitivit	y		-92		dBm	
Co-channel Interferer	nce Rejection		-9		dB	
	+1MHz		+5		dB	25℃,
, r	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

### **Enhanced Data Rate**

Table 3-9

Paramete	Min	Тур	Max	Unit	<b>Test Conditions</b>	
Sensitivit	Sensitivity				dBm	
Co-channel Interferer	nce Rejection		-9		dB	
	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	7



#### Confidential

# 4. Package Information

### 4.1 SOP16(4mm\*4mm)

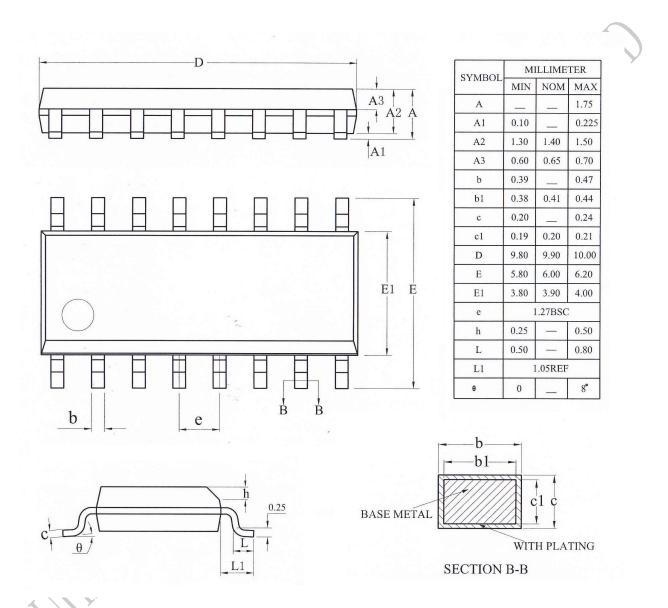
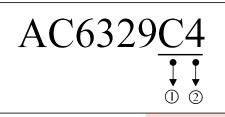


Figure 4-1 AC6329C\_SOP16 Package

# 5. Package Type Specification



- ①Represents different packages
- ②Represents different memory sizes
  - 2: 2Mbit Flash
  - 4: 4Mbit Flash

## 6. Revision History

Date	Revision	Description
2021.03.17	V1.0	Initial Release